NSN 5961-01-082-1985

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-082-1985 **Inclosure Material:** Metal **Overall Length:** 0.297 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute **Special Features:** voltage; junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No